

101725849

CJC



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Diane C. Boyd, et al.

Docket: 16890

Patent No: 7,075,150

Dated: August 04, 2006

Issued: July 11, 2006

**For: ULTRA-THIN SI CHANNEL MOSFET
USING A SELF-ALIGNED OXYGEN IMPLANT
AND DAMASCENE TECHNIQUE**

**Commissioner of Patents
P.O. Box 1450
Alexandria, VA 22313-1450**

REQUEST FOR CERTIFICATE OF CORRECTION

Sir:

**It appearing that errors have been introduced in the course
of printing the Patent issued in the above application, it is respectfully
requested that the Commissioner issue a Certificate of Correction in
the following respects:**

**Column 12, Line 45, Claim 2:
"50.0 mn" should read -- 50.0 nm --**

**Column 12, Line 54, Claim 6:
"The semiconducting" should read -- The semiconducting --**

**Certificate
AUG 22 2006
of Correction**

AUG 23 2006

Column 12, Line 58, Claim 7:

"comrpise a doped region of sai SOI layer"

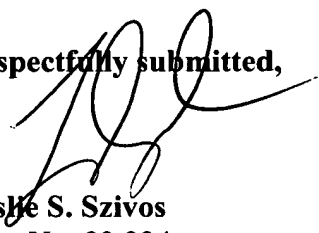
should read

-- comprise a doped region of said SOI layer --

Column 13, Line 5, Claim 11:

"uried sinsulating" should read – buried insulating --

Respectfully submitted,



**Leslie S. Szivos
Reg. No. 39,394**

**Scully, Scott, Murphy & Presser
400 Garden City Plaza, Suite 300
Garden City, New York 11530
(516) 742-4343
LSS/al**

**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**

PATENT NO : 7,075,150
APPLICATION NO : 10/725,849
ISSUE DATE : July 11, 2006
INVENTOR(S) : Diane C. Boyd, et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 12, Line 45, Claim 2:

"50.0 mn" should read -- 50.0 nm --

Column 12, Line 54, Claim 6:

"The semiconducting" should read -- The semiconducting --

Column 12, Line 58, Claim 7:

"comprise a doped region of sai SOI layer"

should read

-- comprise a doped region of said SOI layer --

Column 13, Line 5, Claim 11:

"uried sinsulating" should read -- buried insulating --

MAILING ADDRESS OF SENDER:

Scully, Scott, Murphy & Presser
400 Garden City Plaza, Suite 300
Garden City, New York 11530

PATENT No. 7,075,150

No. of additional copies

1

AUG 23 2006